



PAGE 1 OF 1

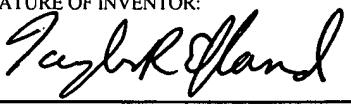
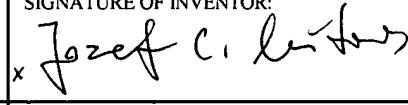
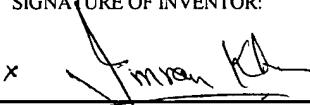
ATTORNEY'S DOCKET NO.

TI-32451

APPLICATION FOR UNITED STATES PATENT DECLARATION AND POWER OF ATTORNEY

As a below named inventor, I declare that my residence, post office address and citizenship are as stated below next to my name; that I verily believe that I am the original, first and sole inventor if only one name is listed below, or an original, first and joint inventor if plural inventors are named below, of the subject matter which is claimed and for which a patent is sought on the invention entitled as set forth below, which is described in the attached specification of Application Serial No. 10/725,642, filed 12/2/03; that I have reviewed and understand the contents of the specification, including the claims, as amended by any amendment specifically referred to in the oath or declaration; that no application for patent or inventor's certificate on this invention has been filed by me or my legal representatives or assigns in any country foreign to the United States of America; and that I acknowledge my duty to disclose information which is material to the patentability of this application in accordance with Title 37, Code of Federal Regulations, Section 1.56;

I further declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true, and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

TITLE OF INVENTION: Low Cost Fabrication Method for High Voltage, High Drain Current MOS Transistor		
POWER OF ATTORNEY: I HEREBY APPOINT PRACTITIONERS AT CUSTOMER NUMBER 23494 TO PROSECUTE THIS APPLICATION AND TRANACT ALL BUSINESS IN THE PATENT AND TRADEMARK OFFICE CONNECTED THEREWITH		
SEND CORRESPONDENCE TO: Gary C. Honeycutt Texas Instruments Incorporated P.O. Box 655474, MS 3999 Dallas, TX 75265	DIRECT TELEPHONE CALLS TO: Gary C. Honeycutt (214) 939-8651	
NAME OF INVENTOR: (1) Taylor R. Efland	NAME OF INVENTOR: (2) Jozef C. Mitros	NAME OF INVENTOR: (3) Imran Khan
RESIDENCE & POST OFFICE ADDRESS: 6404 Oakleaf Lane Richardson, Texas 75082	RESIDENCE & POST OFFICE ADDRESS: 1300 E. Spring Valley Road Dallas, Texas 75081	RESIDENCE & POST OFFICE ADDRESS: 3609 Charleston Drive Richardson, Texas 75082
COUNTRY OF CITIZENSHIP: United States	COUNTRY OF CITIZENSHIP: United States	COUNTRY OF CITIZENSHIP: United States
SIGNATURE OF INVENTOR: 	SIGNATURE OF INVENTOR: 	SIGNATURE OF INVENTOR: 
DATE: <input checked="" type="checkbox"/> 1/5/2004	DATE: <input checked="" type="checkbox"/> 1/8/2004	DATE: <input checked="" type="checkbox"/> 1/9/2004